WHAT IS CLAIMED IS:

- 1 1. A current source comprising:
- a first stage coupled to an input current source, the first stage containing circuitry to
- 3 receive an input current provided by the input current source;
- a second stage coupled to the first stage, the second stage comprising:
- a first transistor and a second transistor serially coupled together, wherein a first terminal of the second transistor is coupled to a second terminal of the first transistor:
- a third transistor having a first terminal coupled to a third terminal of the first transistor; and
- a level shifter coupled to a third terminal of the third transistor and the first terminal of the second transistor, the level shifter containing circuitry to elevate a voltage at a third terminal of the second transistor, wherein the level shifter is arranged in a source-follower configuration.
- 1 2. The current source of claim 1, wherein the level shifter comprises a fourth transistor
- 2 having a first terminal coupled to the third terminal of the third transistor and a third terminal
- 3 coupled to the first terminal of the second transistor.
- 1 3. The current source of claim 2, wherein the first, second, and third transistors are N-type
- 2 MOSFET (metal-oxide semiconductor field-effect transistors), and wherein the fourth transistor
- 3 is a P-type MOSFET.
- 1 4. The current source of claim 2, wherein a first current source is coupled between a
- 2 substrate power supply and the first terminal of the third transistor and a second current source is
- 3 coupled between the substrate power supply and the first terminal of the fourth transistor.

- 1 5. The current source of claim 4, wherein the first current source provides a first current that
- 2 is approximately four times a second current provided by the second current source.
- 1 6. The current source of claim 1, wherein the level shifter comprises a plurality of
- 2 transistors coupled in parallel, wherein each transistor has a first terminal coupled to the third
- 3 terminal of the third transistor and a third terminal coupled to the first terminal of the second
- 4 transistor.
- 1 7. The current source of claim 6, wherein each transistor in the plurality of transistors are P-
- 2 type MOSFET (metal-oxide semiconductor field-effect transistors).
- 1 8. The current source of claim 6, wherein each transistor in the plurality of transistors have
- 2 identical geometries.
- 1 9. The current source of claim 1, wherein the first stage comprises:
- a fifth transistor and a sixth transistor serially coupled together, wherein a first terminal
- 3 of the sixth transistor is coupled to a second terminal of the fifth transistor;
- 4 a seventh transistor having a first terminal coupled to a third terminal of the fifth
- 5 transistor; and
- a second level shifter coupled to a third terminal of the seventh transistor and the first
- 7 terminal of the sixth transistor, the second level shifter containing circuitry to elevate a voltage at
- 8 a third terminal of the sixth transistor.
- 1 10. The current source of claim 9, wherein the second level shifter is arranged in a source-
- 2 follower configuration.

- 1 11. The current source of claim 9, wherein the second level shifter comprises an eighth
- 2 transistor having a first terminal coupled to the third terminal of the seventh transistor and a third
- 3 terminal coupled to the first terminal of the sixth transistor.
- 1 12. The current source of claim 11, wherein the fifth, sixth, and seventh transistors are N-
- 2 type MOSFET (metal-oxide semiconductor field-effect transistors), and wherein the eighth
- 3 transistor is a P-type MOSFET.
- 1 13. The current source of claim 11, wherein a third current source is coupled between a
- 2 substrate power supply and the first terminal of the seventh transistor and a fourth current source
- 3 is coupled between the substrate power supply and the first terminal of the eighth transistor.
- 1 14. The current source of claim 13, wherein the third current source provides a third current
- 2 that is approximately four times a fourth current provided by the fourth current source.
- 1 15. The current source of claim 9, wherein the first terminal of the fifth transistor is coupled
- 2 to the input current source.
- 1 16. The current source of claim 1, wherein the first terminal is a source terminal, the second
- 2 terminal is a drain terminal, and the third terminal is a gate terminal.

a first stage coupled to an input current source, the first stage comprising: 2 3 a first transistor and a second transistor serially coupled together, wherein a first terminal of the second transistor is coupled to a second terminal of the first transistor; 4 a third transistor having a first terminal coupled to a third terminal of the first 5 transistor; 6 7 a second level shifter coupled to a third terminal of the third transistor and the first terminal of the second transistor, the second level shifter containing circuitry to elevate a 8 9 voltage at a third terminal of the second transistor; the current source further comprising a second stage coupled to the first stage, the second 10 11 stage comprising: 12 a fourth transistor and a fifth transistor serially coupled together, wherein a first 13 terminal of the fifth transistor is coupled to a second terminal of the fourth transistor; 14 a sixth transistor having a first terminal coupled to a third terminal of the fourth transistor; and 15 16 a level shifter coupled to a third terminal of the sixth transistor and the first 17 terminal of the fifth transistor, the level shifter containing circuitry to elevate a voltage at a third terminal of the fifth transistor, wherein the level shifter is arranged in a source-follower 18 configuration. 19 1 18. The current source of claim 17, wherein the level shifter comprises a seventh transistor 2 having a first terminal coupled to the third terminal of the sixth transistor and a third terminal

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A current source comprising:

coupled to the first terminal of the fifth transistor and wherein the second level shifter comprises

- 4 an eighth transistor having a first terminal coupled to the third terminal of the third transistor and
- 5 a third terminal coupled to the first terminal of the second transistor.
- 1 19. The current source of claim 18, wherein the seventh and the eighth transistors have
- 2 identical geometries.
- 1 20. The current source of claim 17, wherein the level shifter comprises a plurality of
- 2 transistors coupled in parallel, wherein each transistor has a first terminal coupled to the third
- 3 terminal of the sixth transistor and a third terminal coupled to the first terminal of the fifth
- 4 transistor and wherein the second level shifter comprises a second plurality of transistors coupled
- 5 in parallel, wherein each transistor has a first terminal coupled to the third terminal of the third
- 6 transistor and a third terminal coupled to the first terminal of the second transistor.
- 1 21. The current source of claim 20, wherein each transistor in the plurality of transistors and
- 2 the second plurality of transistors have identical geometries.
- 1 22. The current source of claim 17, wherein the current source is used in a wireless device.

- 1 23. A current source comprising:
- a first stage coupled to an input current source, the first stage containing circuitry to
- 3 receive an input current provided by the input current source;
- a second stage coupled to the first stage, the second stage comprising:
- a first transistor and a second transistor serially coupled together, wherein a first
- 6 terminal of the second transistor is coupled to a second terminal of the first transistor;
- a level shifter coupled to a third terminal of the second transistor and a second
- 8 terminal of the first transistor, the level shifter containing circuitry to elevate a voltage at the
- 9 third terminal of the second transistor, wherein the level shifter is arranged in a source-follower
- 10 configuration; and
- a third transistor having a third terminal coupled to the level shifter.
- 1 24. The current source of claim 23, wherein the level shifter comprises a fourth transistor
- 2 having a second terminal coupled to the third terminal of the second transistor and to the third
- 3 terminal of the third transistor.
- 1 25. The current source of claim 24, wherein the first, second, and third transistors are P-type
- 2 MOSFET (metal-oxide semiconductor field-effect transistors), and wherein the fourth transistor
- 3 is an N-type MOSFET.
- 1 26. The current source of claim 24, wherein a first current source is coupled between a
- 2 substrate ground and the fourth transistor.
- 1 27. The current source of claim 23, wherein the first terminal is a source terminal, the second
- 2 terminal is a drain terminal, and the third terminal is a gate terminal.